

FZT968

12V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- BV_{CEO} > -12V
- I_C = -6A High Continuous Collector Current
- I_{CM} = -20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -170mV @ -2A
- h_{FE} Specified up to -10A for a High Gain Hold Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/)

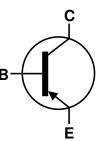
Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.112 grams (Approximate)

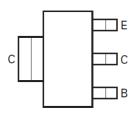
SOT223 (Type DN)



Top View



Device Symbol



Top View Pin-Out

Ordering Information (Note 4)

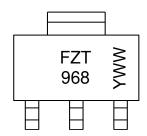
Orderable	Package	Marking	Reel size (inches)	Tape width (mm)	Packing	
Part Number	rackaye		neer size (iliches)	rape width (illin)	Quantity	Carrier
FZT968TA	SOT223 (Type DN)	FZT968	7	12	1,000	Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

SOT223 (Type DN)



FZT 968 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last digit of year (ex: 3 = 2023) WW or $\overline{W}W$ = Week code (01~53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-15	V
Collector-Emitter Voltage	V_{CEO}	-12	V
Emitter-Base Voltage	V _{EBO}	-6	V
Continuous Collector Current	Ic	-6	Α
Peak Pulse Current	I _{CM}	-20	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol Value		Unit	
Power Dissipation	(Note 5)		3.0 24	W
Linear derating factor	(Note 6)	- P _D	1.6 12.8	mW /°C
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{ heta JA}$	42	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	78	°C/W
Thermal Resistance Junction to Lead (Note 7)		$R_{ heta JL}$	8.8	
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.

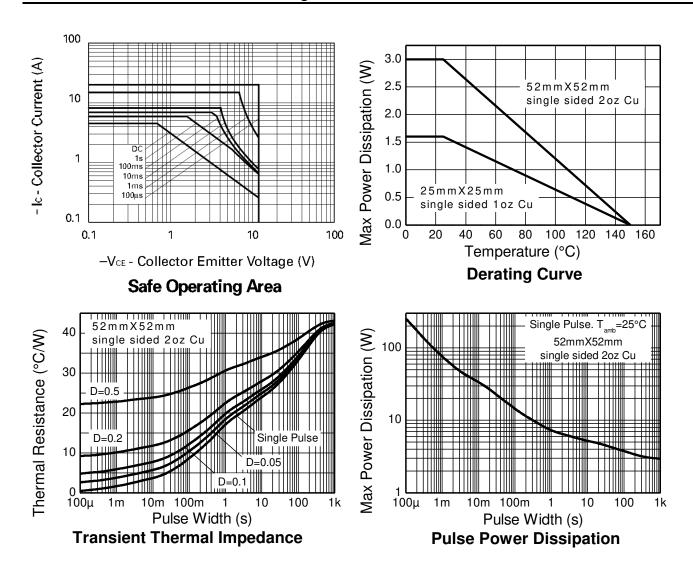
 6. Same as note 5, except the device is mounted on 25mm x 25mm 1oz copper.

 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





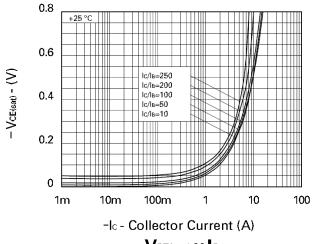
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-15	-28	_	V	$I_C = -100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-12	-20	_	٧	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-6	-8	_	V	$I_E = -100\mu A$
Collector Cutoff Current	I _{CBO}	_	_	-10 -1	nA μA	V _{CB} = -12V V _{CB} = -12V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	_	_	-10	nA	$V_{EB} = -6V$
		300	450	_		$I_C = -10 \text{mA}, V_{CE} = -1 \text{V}$
		300	450	1000		$I_C = -500 \text{mA}, V_{CE} = -1 \text{V}$
DC current transfer Static ratio (Note 9)	h _{FE}	200	300	_] —	I _C = -5A, V _{CE} = -1V
		150	240	_		I _C = -10A, V _{CE} = -1V
		_	50	_		$I_C = -20A$, $V_{CE} = -1V$
		_	-65	-130		$I_C = -500 \text{mA}, I_B = -5 \text{mA}$
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	_	-132	-170	mV	$I_C = -2A$, $I_B = -50mA$
		_	-360	-450		$I_C = -6A$, $I_B = -250mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	-1.05	-1.2	V	$I_C = -6A$, $I_B = -250mA$
Base-Emitter Turn-on Voltage (Note 9)	V _{BE(on)}	_	-0.87	-1.05	V	$I_C = -6A$, $V_{CE} = -1V$
Transitional Frequency (Note 9)	f _T		80		MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V},$ f = 50 MHz
Output capacitance	Cobo	_	161		pF	V _{CB} = -20V, f = 1MHz
Switching Time	ton	_	120	_	ns	V _{CC} = -10V, I _C = -4A,
Switching Time	t _{off}		116		115	$I_{B1} = -I_{B2} = -400 \text{mA}$

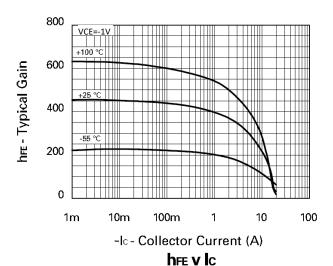
Note: 9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



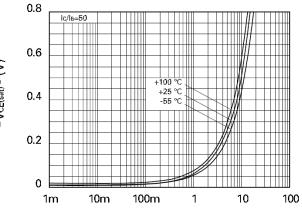




1.4 VCE=-1V -55 °C +25 °C - VBE(on) - (V) 0.7 100m 10 1m 10m 100 -IC - Collector Current (A)

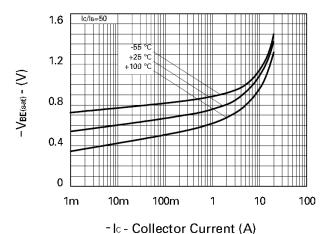
VBE(on) v lc

-VCE(sat) - (V)



-Ic - Collector Current (A)





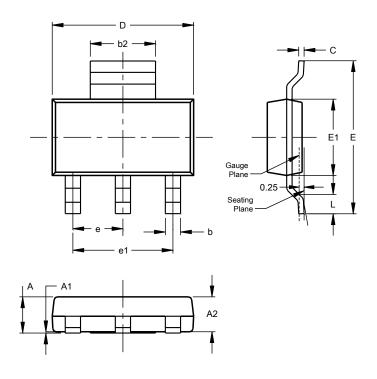
VBE(sat) V IC



Package Outline Dimensions

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

SOT223 (Type DN)

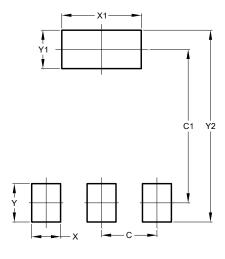


SOT223 (Type DN)					
Dim	Min	Max	Тур		
Α		1.70			
A 1	0.01	0.15			
A2	1.50	1.68	1.60		
b	0.60	0.80	0.70		
b2	2.90	3.10			
С	0.20	0.32			
D	6.30	6.70			
Е	6.70	7.30			
E1	3.30	3.70			
е			2.30		
e1			4.60		
L	0.85				
All Dimensions in mm					

Suggested Pad Layout

Please see https://www.diodes.com/design/support/packaging/diodes-packaging/ for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Υ	1.60
Y1	1.60
Y2	8.00



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